T-52-11

CY10E383
CY101E383

CYPRESS SEMICONDUCTOR

ECL/TTL Translator and High-Speed Bus Driver

Features

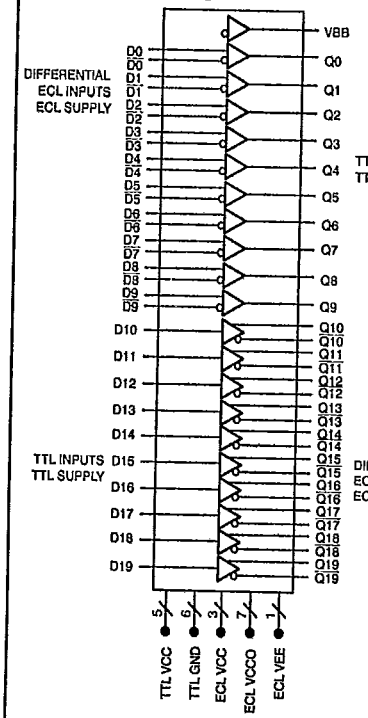
- BiCMOS for optimum speed/power
- High speed (max.)
  - —2.5 ns t_{PD} TTL-to-ECL
  - —3 ns t_{PD} ECL-to-TTL
- Low skew < ± 1 ns
- Can operate on single +5V supply
- Full-duplex ECL/TTL data transmission
- Internal 2 kΩ ECL pull-down resistors on each ECL output
- Surface-mount PLCC/CLCC package
- V_{BB} ECL reference voltage output
- Single- or dual-supply operation
- Capable of greater than 2001V ESD
- ECL cable/twisted pair driver

Functional Description

The CY10/101E383 is a new-generation TTL-to-ECL and ECL-to-TTL logic level translator designed for high-performance systems. The device contains ten independent TTL-to-ECL and ten independent ECL-to-TTL translators for high-speed full-duplex data transmission, mixed logic, and bus applications. The CY10/101E383 is especially suited to drive ECL backplanes between TTL boards. The CY10/101E383 is implemented with differential ECL I/O to provide balanced low noise operation over controlled impedance buses between TTL and/or ECL subsystems. In addition, the device has internal output 2 kΩ pull-down resistors tied to V_{EE} to decrease the number of external components. For system testing purposes or for driving light loads, the 2 kΩ is used as the only termination thereby eliminating up to 20 external resistors. The part meets standard 10K/10KH and 100K logic levels with the internal pull-down while driving 50Ω to −2V.

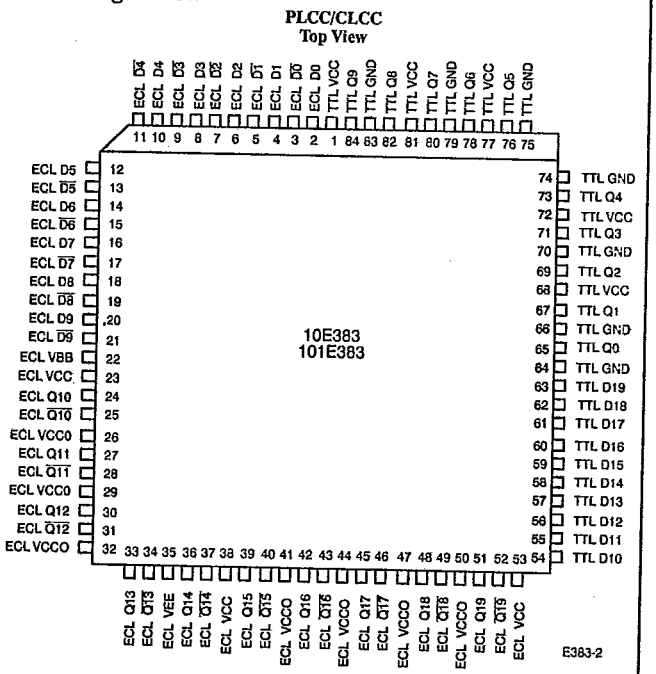
The device is designed with ample ground pins to reduce bounce, and has separate ECL and TTL power/ground pins to reduce noise coupling between logic families. The parts can operate in single- or dual-supply configurations while maintaining absolute 10K/10KH and 100K level swings. The translators are offered in standard 10K/10KH (10E) and 100K (101E) ECL-compatible versions with −5.2V or −4.5V power supply. The TTL I/O is fully TTL compatible. The CY10/101E383 is packaged in 84-pin surface-mountable PLCCs and CLCCs.

Logic Block Diagram



Pin Configuration

PLCC/CLCC
Top View



10

ECL

CYPRESS SEMICONDUCTOR

T-52-11

CY10E383
CY101E383

Selection Guide

	10E383–2 101E383–2	10E383–3 101E383–3
Maximum Propagation Delay Time (ns) (TTL to ECL)	2.5	3
Maximum Propagation Delay Time (ns) (ECL to TTL)	3	4
Maximum Operating Current (mA) Sum of I_{EE} and I_{CC}	270	270

Shaded area contains preliminary information.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... −65°C to +150°C

Ambient Temperature with Power Applied ..... −55°C to +125°C

TTL Supply Voltage to Ground Potential ... −0.5V to +7.0V

TTL DC Input Voltage ..... −3.0V to +7.0V

ECL Supply Voltage V_{EE} to ECL V_{CC} ..... −7.0V to +0.5V

ECL Input Voltage ..... V_{EE} to +0.5V

ECL Output Current ..... −50 mA

Static Discharge Voltage ..... > 2001V (per MIL-STD-883, Method 3015)

Latch-Up Current ..... > 200 mA

Operating Range

Range	I/O	Version	Ambient Temperature	ECL V_{EE}	TTL V_{CC}
Commercial	10K 10KH	10E	0°C to +75°C	−5.2V ± 5%	5V ± 5%
Commercial	100K	101E	0°C to +85°C	−4.2V to −5.46V	5V ± 5%
Military	10K 10KH	10E	−55°C to +125°C case	−5.2V ± 5%	5V ± 5%

Shaded area contains preliminary information.

ECL Electrical Characteristics Over the Operating Range[1]

Parameters	Description	Test Conditions	Temperature[2]	10E383 Min.	10E383 Max.	101E383 Min.	101E383 Max.	Units
V_{OH}	Output HIGH Voltage	10E, R_L = 50Ω to −2V V_{IN} = V_{IH} Min. or V_{IL} Max.	T_C = −55°C	−1140	−900			mV
			T_A = 0°C	−1000	−840			mV
			T_A = +25°C	−960	−810			mV
			T_A = +75°C	−900	−735			mV
			T_C = +125°C	−880	−700			mV
		101E R_L = 50Ω to −2V, V_{IN} = V_{IH} Min. or V_{IL} Max.	T_A = 0°C to 85°C			−1025	−880	mV
V_{OL}	Output LOW Voltage	10E, R_L = 50Ω to −2V V_{IN} = V_{IH} Min. or V_{IL} Max.	T_C = −55°C	−1920	−1670			mV
			T_A = 0°C	−1870	−1665			mV
			T_A = +25°C	−1850	−1650			mV
			T_A = +75°C	−1830	−1625			mV
			T_C = +125°C	−1830	−1610			mV
		101E R_L = 50Ω to −2V, V_{IN} = V_{IH} Min. or V_{IL} Max.	T_A = 0°C to 85°C			−1810	−1620	mV
V_{IH}	Input HIGH Voltage	10E	T_C = −55°C	−1260	−900			mV
			T_A = 0°C	−1170	−840			mV
			T_A = +25°C	−1130	−810			mV
			T_A = +75°C	−1070	−720			mV
			T_C = +125°C	−1030	−700			mV
		101E	T_A = 0°C to 85°C			−1165	−880	mV
V_{IL}	Input LOW Voltage	10E	T_C = −55°C	−1950	−1540			mV
			T_A = 0°C	−1950	−1480			mV
			T_A = +25°C	−1950	−1475			mV
			T_A = +75°C	−1950	−1450			mV
			T_C = +125°C	−1950	−1450			mV
		101E	T_A = 0°C to 85°C			−1810	−1475	mV

CYPRESS SEMICONDUCTOR

T-52-11

ECL Electrical Characteristics Over the Operating Range[1] (continued)

Parameters	Description	Test Conditions	Temperature[2]	Min.	Max.	Min.	Max.	Units
V_{BB}	Output Reference Voltage	10E[3]	T_A = 0°C to 75°C	−1.37	−1.18			V
			T_C = −55°C	−1.46	−1.32			
			T_C = +125°C	−1.29	−1.14			
		101E[3]	T_A = 0°C to 85°C			−1.40	−1.23	
V_{cm}[4]	Common Mode Voltage	±V_{cm} with respect to V_{BB}			1.0		1.0	V
V_{diff}	Input Voltage Differential	Required for Full Output Swing		150		150		mV
I_{IH}	Input HIGH Current	V_{IN} = V_{IH} Max.			220		220	µA
I_{IL}	Input LOW Current	V_{IN} = V_{IL} Min.		−0.5	170	−0.5	170	µA
R_{PD}	Pull-Down Resistor	Connected from All ECL Outputs to V_{EE}	T_A = 0°C to 75°C	1.6	2.4			kΩ
			T_C = −55°C to +125°C	1.6	2.4			
			T_A = 0°C to 85°C			1.6	2.4	
I_{EE}	Supply Current (All inputs and outputs open)				−180		−180	mA

Shaded area contains preliminary information.

TTL Electrical Characteristics Over the Operating Range[1]

Parameters	Description	Test Conditions	10E383 101E383 Min.	10E383 101E383 Max.	Units
V_{OH}	Output HIGH Voltage	V_{CC} = Min., I_{OH} = −3.2 mA	2.4		V
V_{OL}	Output LOW Voltage	V_{CC} = Max., I_{OL} = 16.0 mA		0.5	V
V_{IH}	Input HIGH Voltage[5]		2.0		V
V_{IL}	Input LOW Voltage[5]			0.8	V
V_{CD}	Input Clamp Diode Voltage	I_{IN} = −10 mA	−1.5		V
I_{OS}	Output Short-Circuit Current	V_{CC} = Max., V_{OUT} = 0.5V[6]	−180	−40	mA
I_{IX}	Input Load Current[7]	GND ≤ V_I ≤ V_{CC}	−250	+20	µA
I_{CC}	V_{CC} Operating Supply Current	V_{CC} = Max., I_{OUT} = 0 mA, f = f max.		90	mA

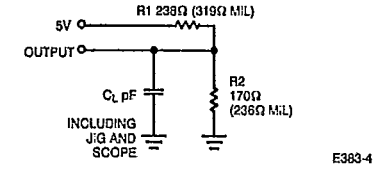
Capacitance

Parameters	Description	Test Conditions	Max.	Units
C_{IN}	Input Capacitance		4	pF
C_{OUT}	Output Capacitance		5	pF

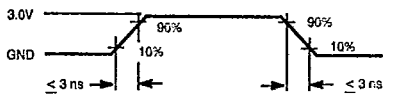
Notes:
1. See AC Test Load and Waveform for test conditions.
2. Commercial grade is specified as ambient temperature with transverse air flow greater than 500 linear feet per minute. Military grade is specified as case temperature.
3. Max. I_{BB} = −1 mA.
4. The internal gain of the CY101/10E383 guarantees that the output voltage will not change for common mode signals to ±1V. Therefore, input C_{MRR} is infinite within the common mode range.
5. These are absolute values with respect to device ground.
6. Not more than one output should be tested at a time. Duration of the short should not be more than one second.
7. I/O pin leakage is the worst case of I_{IX} (where X = H or L).

ECL

TTL AC Test Load and Waveform[8]

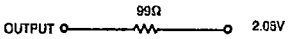


E383-4

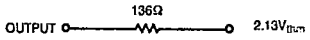


E383-3

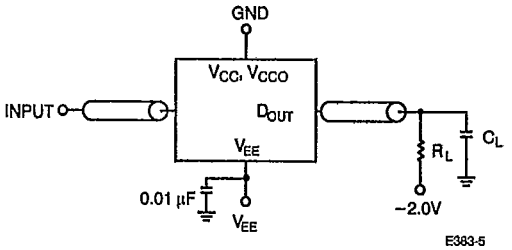
Equivalent to: THÉVENIN EQUIVALENT (Commercial)



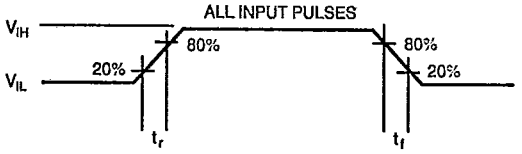
THÉVENIN EQUIVALENT (Military)



ECL AC Test Load and Waveform[9, 10, 11, 12, 13, 14]



E383-5



E383-6

Notes:

8. TTL test conditions assume signal transition times of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0V, and output loading of the specified I_{OL}/I_{OH}, and C_L = 10 pF.
9. V_{IL} = V_{IL} Min., V_{IH} = V_{IH} Max. on 10KH version.
10. V_{IL} = −1.7V, V_{IH} = −0.9V on 101E version
11. ECL R_L = 50Ω, C_L < 5 pF (includes fixture and stray capacitance).
12. All coaxial cables should be 50Ω with equal lengths. The delay of the coaxial cables should be "nulled" out of the measurement.
13. $t_r = t_f = 0.7$ ns
14. All timing measurements are made from the 50% point of all waveforms.

ECL-to-TTL Switching Characteristics Over the Operating Range

Parameters	Description	Test Conditions	10E383−2 101E383−2		10E383−3 101E383−3		Units
			Min.	Max.	Min.	Max.	
t_{pLH}	Propagation Delay Time	D_n, $\overline{D}_n$ to Q_n		3		4	ns
t_{pHL}	Propagation Delay Time	D_n, $\overline{D}_n$ to Q_n		3		4	ns

Shaded area contains preliminary information.

TTL-to-ECL Switching Characteristics Over the Operating Range

Parameters	Description	Test Conditions	10E383−2 101E383−2		10E383−3 101E383−3		Units
			Min.	Max.	Min.	Max.	
t_{pLH}	Propagation Delay Time	D_n to Q_n, $\overline{Q}_n$		2.5		3	ns
t_{pHL}	Propagation Delay Time	D_n to Q_n, $\overline{Q}_n$		2.5		3	ns
t_r	Output Rise Time	20% to 80%	0.35	1.7	0.35	1.7	ns
t_f	Output Fall Time	20% to 80%	0.35	1.7	0.35	1.7	ns

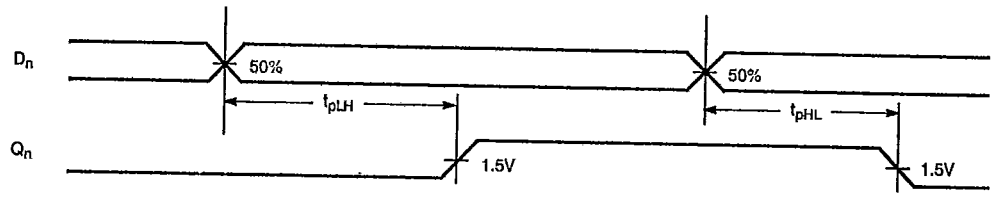
Shaded area contains preliminary information.

Skew Time Switching Characteristics (Same test conditions as TTL-to-ECL and ECL-to-TTL Electrical Characteristics)

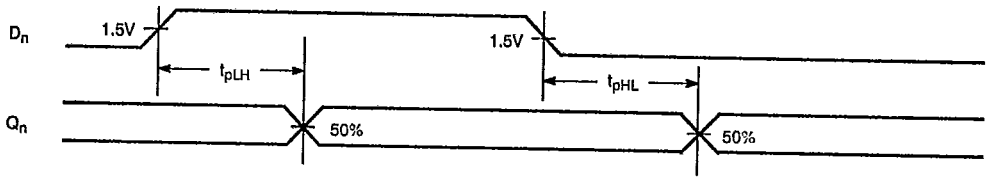
Symbol	Characteristic	Test Conditions	Min.	Max.	Units
t_{SKT}	Data Skew Time ECL-to-TTL	$TTLQ_n$ to $TTLQ_{n+1}$		±1	ns
t_{SKE}	Data Skew Time TTL-to-ECL	$ECLQ_n$, $\overline{Q}_n$ to $ECLQ_{n+1}$, $\overline{Q}_{n+1}$		±1	ns

Switching Waveforms

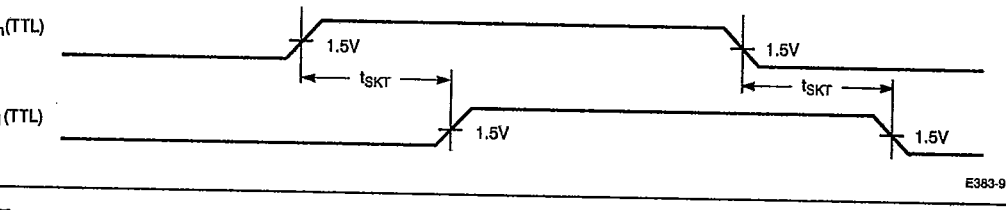
ECL-to-TTL Timing



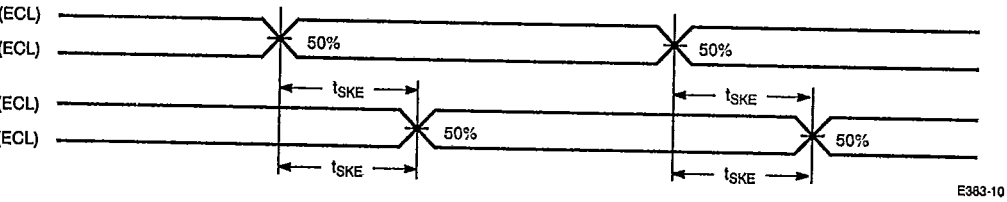
TTL-to-ECL Timing



Skew Test (t_{SKT})
TTL_{Qn}-to-TTL_{Qn+1}



Skew Test (t_{SKE})
ECL_{Qn}, $\overline{Q}_n$-to-ECL_{Qn+1}, $\overline{Q}_{n+1}$



ECL-to-TTL Truth Table

Inputs		Outputs
ECL D_n	ECL $\overline{D}_n$	TTL Q_n
Open	Open	L
L	H	L
H	L	H

TTL-to-ECL Truth Table

Inputs	Outputs	
TTL D_n	ECL Q_n	ECL $\overline{Q}_n$
L	L	H
H	H	L

10

ECL

Nominal Voltages

The CY101/10E383 can be used in dual ±5V or single +5V supply systems. The supply pins should be connected as shown in *Tables 1* and *2*. This connection technique involves shifting up all ECL supply pins by 5V. When operating in single-supply systems, the ECL terminationvoltage level must also be shifted up by adding 5V. For example, if the termination is 50 ohms to −2V in a dual-supply system, the single +5V system should have 50 ohms to +3V. If the termination is a thévenin type, then the resistor tied to ground is now at +5V and the resistor tied to −5V is now at ground potential. Consideration should be given to the power supply so that adequate bypassing is made to isolate the ECL output switching noise from the supply. Having separate TTL and ECL +5V supply lines will help to reduce the noise. *Table 3* shows the CY10E383 nominal voltages applied in a 10K system.

Table 1. CY101E383 Nominal Voltages Applied in 100K System

Supply Pin	Single-Supply System	Dual-Supply System
TTL V_{CC}	+5.0V	+5.0V
TTL GND	0.0V	0.0V
ECL V_{CC}/V_{CCO}	+5.0V	0.0V
ECL V_{EE}	0.0V	−4.5V

Table 2. CY101E383 Nominal Voltages Applied in 101K System

Supply Pin	Single-Supply System	Dual-Supply System
TTL V_{CC}	+5.0V	+5.0V
TTL GND	0.0V	0.0V
ECL V_{CC}/V_{CCO}	+5.0V	0.0V
ECL V_{EE}	0.0V	−5.2V

Table 3. CY10E383 Nominal Voltages Applied in 10K System

Supply Pin	Single-Supply System	Dual-Supply System
TTL V_{CC}	+5.0V	+5.0V
TTL GND	0.0V	0.0V
ECL V_{CC}/V_{CCO}	+5.0V	0.0V
ECL V_{EE}	0.0V	−5.2V

Ordering Information

Speed (ns)	Ordering Code	Package Type	Operating Range
2	CY10E383−2JC	J83	Commercial
	CY101E383−2JC	J83	
3	CY10E383−3JC	J83	Commercial
	CY101E383−3JC	J83	
	CY10E383−3YMB	Y84	Military

Shaded area contains preliminary information.

Document #: 38−A−00023−C